## Importance of interorbital charge transfers for the metal-to-insulator transition of B aV S $_3$

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The underlying mechanism of the metal-to-insulator transition (M IT) in BaVS<sub>3</sub> is investigated, using dynamical mean-eld theory in combination with density functional theory. It is shown that correlation e ects are responsible for a strong charge redistribution, which lowers the occupancy of the broader A<sub>1g</sub> band in favor of the narrow er E<sub>g</sub> bands. This resolves several discrepancies between band theory and the experimental ndings, such as the observed value of the charge-density wave ordering vector associated with the M IT, and the presence of local moments in the metallic phase.

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The structural, electronic and magnetic properties of the vanadium sulphide compound BaVS3 raise several puzzling questions [1, 2]. At room temperature, this material crystallizes in a hexagonal (P 63=mm c) structure [3], in which straight chains of face-sharing  $VS_6$ octahedra are directed along the c-axis. At  $T_{\rm s}$  240 K the crystal structure transforms into an orthorhombic  $(C m c_{2_1})$  structure [4], thereby creating an anisotropy in the ab-plane (i.e., perpendicular to the chain direction) and a zigzag distortion of the VS<sub>3</sub> chains in the bc-plane. Additionally, the Hall coe cient changes sign from negative to positive at  $T_s$  [2]. On further cooling the system displays a metal-to-insulator transition (MII) at 70 K. Remarkably, this transition is second-order T<sub>M IT</sub> and is not accompanied by magnetic ordering. Only below T<sub>x</sub> 30 K indications for an incommensurate antiferrom agnetic order exist [5].

Form et al. [6] have found that the M II can be driven to T = 0 by applying pressure [7]. Further recent experiments [8, 9] have demonstrated that the MIT is in fact associated with a structural transition. These studies establish that a commensurate structuralmodulation sets in, corresponding to a reduced wave vector  $q = (1, 0, \frac{1}{2})_0$  in the orthorhom bic cell. Furtherm ore, the X-ray di use scattering experiments of Fagot et al. [9] reveal a large uctuation regime with critical wave vector  $q_c = 0.5c$  (here c is the reciprocal unit vector along the c-axis of the orthorhom bic system ), extending up to 170 K into the metallic phase. In the same tem perature range the Hall coe cient is strongly increasing [2]. This regime might be interpreted as a precursor of the charge density wave (CDW) instability, rem iniscent of the large uctuations in a quasi one-dimensional (1D) metal in the vicinity of a Peierls transition. It should be kept in m ind how ever that the conduction an isotropy within the system is not strongly pronounced ( $_{c}=_{a}$  3-4) [10], making 1D interpretations questionable. The \m etallic" phase above T<sub>M II</sub> displays several other unusual properties [7, 10]. The resistivity is rather high (a few m cm) and metallic-like (d =dT > 0) only above 150 K. It displays a weak m inimum at this tem perature, below which it increases upon further cooling. M ost interestingly, this phase displays local m om ents, as revealed by the Curie-W eiss form of the magnetic susceptibility. The elective m om ent corresponds approximately to one localized spin-1=2 per two V sites. Since the form all valence is V<sup>4+</sup>, corresponding to one electron in the 3d-shell, this can be interpreted as the elective localization of half of the electrons. At  $T_{M IT}$ , the susceptibility rapidly drops, and the electronic entropy is strongly suppressed [11].

In the hexagonal high-T phase the low-lying V (3d) levels consist of an  $A_{1q}$  state and two degenerate  $E_q$ states. A further splitting of the degenerate states occurs in the orthorhom bic phase. First-principles calculations of the electronic structure of  $BaVS_3$ , based on density functional theory (DFT) in the local (spin) density approximation (L(S)DA), have been performed in Refs. [12, 13, 14]. For both phases, the calculations do yield a V (3d)-S (3p) hybridization which is strong enough to account for the weak an isotropy of the transport properties. No band-gap opening has been reached within L(S)DA. Instead, very narrow  $E_{g}$  bands right at the Ferm i level, and a nearly lled dispersive band with mainly  $A_{1q}$  character extending along the c direction have been found. This is consistent with a simple model proposed early on by M assence et al. [15]. How ever, the occupancy of the narrow E<sub>g</sub> bands found within LDA is too low to account for the observed localm om ent in the m etallic phase. The nature of the CDW instability is also left unexplained by the DFT calculations. Indeed, the calculated value of the Ferm i wave vector of the broad  $A_{1q}$  band is found to be  $2k_F^{LDA}$  (0:94c [13], while the observed wave vector of the instability is  $q_c = 0.5c$  [9]. Therefore, the simple picture of a CDW at  $q_c = 2k_F$  associated only with the A<sub>1g</sub> band is untenable within LDA. It is likely that the E<sub>q</sub> states also participate in the instability, but the LDA band structure does not provide a Ferm i-surface nesting compatible with the experim ental q value [1]. Hence, ab-initio calculations based on L (S)DA are not su cient to explain the electronic struc-

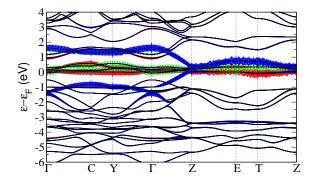


FIG.1: LDA band structure for BaV  $S_3$  in the Cm  $c_{21}$  structure. Also shown are the fatbands (see text) for the  $A_{1g}$  (blue/full dark),  $E_{g1}$  (red/full grey) and  $E_{g2}$  (green/dashed grey) orbital of the V atom s.

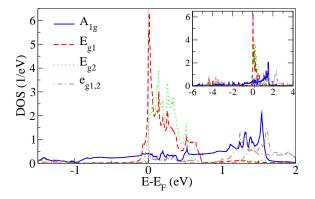


FIG. 2: Angular momentum-resolved LDA-DOS of the symmetry-adapted V (3d) states.

ture of BaV  $S_3$ . By using static DFT + U schemes a band gap was obtained [16]. However, this required to enforce m agnetic order, hence leaving the question of the mechanism of the transition into the paramagnetic insulator unanswered [24].

In this letter, we present calculations in the fram ework of dynam icalm ean eld theory (DMFT), using the LDA electronic structure as a starting point. On the basis of this LDA+DMFT treatment we propose correlation effects in a multi-orbital context as an explanation for the discrepancies between band theory predictions and experiments. Speci cally, we show that interorbital charge transfers occur, driven by the on-site H und's coupling. This lowers the occupancy of the A<sub>1g</sub> orbital in favor of the E<sub>g</sub>'s, hence shifting k<sub>F</sub> (A<sub>1g</sub>) towards lower values. From a calculation of the local susceptibilities, we demonstrate that localmom ents are form ed in the m etallic phase, due to the low quasiparticle coherence scale induced by the strong correlations (particularly for the narrow E<sub>g</sub> bands).

On Fig. 1 the band structure of  $BaVS_3$  calculated within LDA for the T = 100 K orthorhom bic (Cm c2<sub>1</sub>) crystal structure [4] is displayed. The calculations were performed by using norm-conserving pseudopotentials

and a mixed basis consisting of plane waves and localized functions [17]. The results are consistent with previous work [12, 13, 14]. The symmetry-adapted V (3d)-basis f m g was obtained by diagonalising the orbital density  $_{kb} f_k^{b} h_k^{b} M i M _{jk}^{0} j_k^{b} i, where _k^{b} stands$ matrix n<sub>M M</sub> o for the pseudo crystal wave function for wave vector k and band b, and M  $_{\rm M}$   $^{0}$  denote the cubic harm onics for l= 2. Being directed along the chain direction between pairs of V atom s, the  $A_{1q}$  orbital has mainly  $d_{z^2}$  character. In contrast, the  $E_{\,\rm q}\,$  states, linear combinations of  $d_{yz}$ ;  $d_{x^2 y^2}$  and  $d_{z^2}$  (E<sub>q1</sub>) as well as  $d_{xy}$  and  $d_{xz}$  (E<sub>q2</sub>), only weakly hybridize with their surrounding. The orbitals of the remaining ea manifold point mainly towards the sulphur atom s, which results in a large energy splitting, leading to a sm aller (larger) contribution to the occupied (unoccupied) states well below (above) " $_{\rm F}$  . Hence, the  $e_{\alpha}$  states do not have a major in uence on the essential physics around the MIT. Note that in the orthorhom bic structure (as already in the hexagonal one), the unit-cell contains two form ula units, with the two Vsites equivalent by sym m etry. The high-sym m etry points -C-Y in the Brillouin Zone (BZ) de nea triangle in the  $k_z = 0$  plane, whereas Z-E-T is the analogous shifted triangle in the  $k_z = 0.5c$  plane. The -Z line corresponds to the propagation along the c-axis. We have used a \fatband" representation associated with the  $fA_{1g}; E_{g}g$ orbitals on Fig. 1 in which the width is proportional to the amount of orbital character of each band at a given k-point. Thus, one can identify that the narrow bands at the Ferm i level are associated with the  $E_{\rm q}$  orbitals. A long -Z starting at around -1 eV, one observes the dispersive band with strong  $A_{1q}$  character that crosses " $_{\rm F}$  close to the edge of the BZ. Hence the -Z portion of that band is almost lled, with  $2k_F'$  0:94c as mentioned above. The E<sub>g2</sub> electron pocket at the -point is absent for the hexagonal high-T structure (see also [13]). Its existence m ight be related to the hole-like transport below  $T_S$  as revealed from Hallm easurements [2]. The partial density of states (DOS) for each orbital displayed on Fig. 2, show a rather broad  $A_{1q}$  DOS while the  $E_q$ 's yield very narrow peaks right at and above  $\mathrm{E}_{\,\mathrm{F}}$  .

Recently, it has become possible to investigate correlation e ects in a realistic setting by combining LDA with DMFT [18, 19]. Starting from the LDA ham iltonian  $H_{mm^0}^{\text{LDA}}(k)$  expressed in a localized basis set, manybody terms are introduced, leading to a self-energy matrix mm^ which is taken to be local (k-independent) but fully frequency-dependent. In the present work, we use a simplied implementation of the LDA + DMFT approach, which is geared at keeping those physical ingredients which are important for the physics of BaVS<sub>3</sub> close to the MIT. Speci cally, we work within an elective 3band model, whereby the LDA electronic structure enters via the DOS in the relevant energy window around the Ferm i level. The elective bands are derived from the symmetry-adapted  $fA_{1q}; E_{qg}$  states, thus non-diagonal

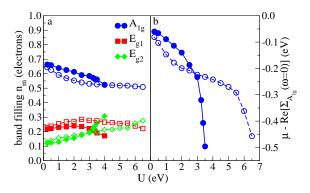


FIG.3: (a) Band llings at =  $(k_B T)^{-1} = 15 \text{ eV}^{-1}$  (T = 774 K) for the e ective bands within LDA + DMFT. (b) Corresponding shift of the Fermi level for the A<sub>1g</sub> band (note that  $\mathbf{w}_{k_F}^{(LDA)} = 0$ ). Filled symbols: U=J=7, open symbols: U=J=4.

self-energy term s m fm o are negligible. A physically adequate 'em pirical downfolding' procedure was used in order to construct the e ective 3-band DOS.First, we took care of the  $3d^1$  character. The location and width ( 2.2 eV) of the energy window were chosen such that the total DOS accom odates two electrons below and ten electrons above the Ferm i level (per two V). Since the  $e_{\alpha}$  bands are hardly relevant and of m inor weight close to  $E_{\rm F}$  , they were hybridized with the  $E_{q}$  bands as suggested from the resolved partial DOS on Fig. 2. The contribution of these new  $E_{q}$  bands was substracted from the totalDOS normalized to a single formula unit of  $BaVS_3$  within the chosen energy window. The resulting di erence was identi ed as the new downfolded  $A_{1q}$  band, since the  $A_{1q}$  orbital substantially hybridizes with the S (3p) orbitals. F inally, the self-energies m associated with these e ective bands are calculated from LDA+DMFT where the selfconsistency condition is expressed as an integral over the e ective partial DOS D $_{\rm m}^{\rm LDA}$  ("). The on-site interaction matrix was parametrised as:  $U_{mm}^{"\#} = U$ ,  $U_{m6m0}^{"\#} = U$  2J and  $U_{m \notin m^{\circ}}^{""(\#\#)} = U$  3J, with U the on-site C oulom b repulsion and J the local H und's rule coupling. The DM FT local impurity problem was solved using the quantum Monte-Carlo (QMC) Hirsch-Fye algorithm. Up to 128 slices in imaginary time and at most 10° sweeps were used [25].

F ig. 3a displays our results for the occupancies of each orbital, as a function of U. In the absence of a precise determ ination of this parameter from either experiments (e.g., photoem ission) or theory (constrained LDA methods tend to underestimate the screening for metals), we varied U over a rather large range of values. The ratio U=J was chosen to be xed, and two series were studied: U=J=7 and U=J=4, corresponding to a weaker and stronger H und's coupling, respectively. The orbital occupancies in our elective 3-band model, at the LDA level (i.e., for U=0) read:  $n(A_{1g})=0.712$ ,  $n(E_{g1})=0.207$  and  $n(E_{g2})=0.081$ . The main elect apparent on Fig. 3a is

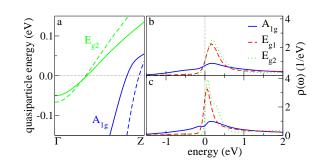


FIG. 4: LDA+DMFT spectral data for U = 3.5 eV, U = J = 4. (a) V (3d) low energy quasiparticle bands along -Z in LDA (dashed lines) and LDA+DMFT (solid lines) for T = 332 K. (b,c) integrated spectral function (!) for a single form ula unit of BaVS<sub>3</sub> at T = 1160 K (b) and T = 332 K (c).

that moderate correlations tend to bring the occupancies of each orbital closer to one another, i.e., to decrease the population of the \extended" orbital  $A_{1q}$  and to increase the occupancy of each E q orbital. For strong correlations, values close to  $n (A_{1g})' n (E_{g1}) + n (E_{g2})' 0.5$  are obtained in the DMFT calculation, corresponding to a half-lled band. In the absence of correlations, it pays to occupy dom inantly the broad A<sub>1g</sub> band, which provides the largest kinetic energy gain, while in the presence of correlations this has to be balanced versus the potential energy cost. The Hund's coupling clearly favors such an interorbital charge redistribution, as also pointed out recently in the context of ruthenates [20]. For larger U, band-narrowing e ects reduce the kinetic energy of the A<sub>1q</sub> band, hence also reducing its occupancy [21] in favor of E<sub>q</sub>. As expected, a M ott insulating state is obtained when U is increased beyond a critical value, which is found to depend strongly on J (the range of U's displayed in Fig. 3 corresponds to the metallic regime for each series, on which we focus in this paper).

O ur calculations reveal that the depletion of the  $A_{1\alpha}$ band is accompanied by a reduction of the corresponding  $k_F$  along the -Z direction. Note that the Luttinger theorem [22] does not apply separately for each band but only relates the total Ferm i surface volum e to the total occupancy). W hile a full determ ination of the quasiparticle (QP) band structure in the interacting system requires a determ ination of the real-frequency self-energy, we can extract the low-energy expansion of this quantity from our QMC calculation, in the form : Re  $_{m}$  (! + i0<sup>+</sup>)' Re  $_{m}$  (0) + ! (1 1=Z\_{m}) + ,with Z the QP residue associated with each orbital. The poles of the G reen's function determ ine the Q P dispersion re- $\hat{Z} \mathbb{H}_{k}^{\text{LDA}} + \text{Re}(0)$ lation: det [ $!_k$ ]]= 0, with the chemical potential. Focusing rst on the Alg sheet of the Ferm i surface, within our diagonal formulation the location of the Ferm i wave vector in the interacting system is determined by:  ${}^{\rm LDA}_{\rm A_{1g}}$  (k\_F )= Re Alg (0). This quantity therefore yields the energy shift of the A<sub>1g</sub> band

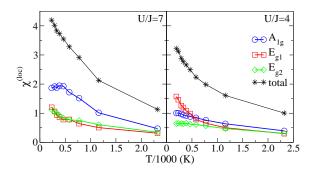


FIG. 5: T-dependent local spin susceptibilities for U = 3.5 eV, according to the normalization  $^{(loc)} = {}_0 d k \hat{s}_z (0) \hat{s}_z ()$  i, where  $\hat{s}_z$  denotes the z-component of the spin operator.

at the Ferm i surface crossing, as com pared to LDA. It is depicted in Fig. 3b as a function of U. On Fig. 4a, we display (for U = 3.5eV and U=J=4) the QP bands that cross the Ferm i level along -Z in a narrow energy range around "<sub>F</sub>. The QP bands are obtained by perform - ing a perturbative expansion of the pole equation above, which yields:  $!_{bk} = {}_m C_{m\,k}^b Z_m [!_{bk}^{LDA} + Re_m (0)]$  with  $C_{m\,k}^b j_n j_j^b the LDA$  orbital weight. From these two gures, it is clear that  $k_F (A_{1g})$  is reduced in com - parison to the LDA value, in line with the global charge transfer from  $A_{1g}$  to  $E_g$ . This opens new possibilities for the CDW instability, in particular for the nesting condition.

The enhanced population of the narrow  $E_q$  bands, as wellas the correlation-induced reduction of its bandwidth (see Fig. 4a) provide an explanation for the local moments observed in the metallic phase. To support this, we have calculated (Fig. 5) the local susceptibility associated with each orbital  $m^{(loc)}$  $_{q}Re[m(q;!=0)].$ For both values of U=J, the susceptibility of the  $A_{1q}$ band saturates to a Pauli-like value at low tem peratures. In contrast,  $^{(loc)}$  of the  $E_{q}$  orbitals strongly increases as T is low ered (except for the low - lled  $E_{q2}$  orbital at U=J=4). This is because the coherence tem perature below which quasiparticles form is much lower for the  $E_{\alpha}$ orbitals than for the  $A_{1g}$  . A coordingly, our calculation of the integrated spectral functions (Fig. 4b,c) reveals a strong T-dependence of the E<sub>q</sub> QP peak. Som e di erences between the two series are clear from Fig. 5. For U=J=7, the system is very close to the M ott transition. Thus the  $A_{1q}$  electrons also act as local moments over part of the tem perature range, while for U=J=4, the T-dependence of the total local susceptibility is almost entirely due to the E<sub>al</sub> electrons. W hich of the two situations is closest to the physics of BaVS3 does require further investigations, albeit som e experim ental indications point at the second possibility [23].

In conclusion, we have shown that charge redistributions due to correlations low er the occupancy of the broad  $A_{1q}$  band in favor of the narrow  $E_q$ 's, in comparison to LDA calculations. This explains the presence of localm om ents in the m etallic phase and paves the road towards a full understanding of the CDW instability of this m aterial. O rbital-selective experim ental probes are highly desirable in order to put to a test the conclusions of the present work. Am ong several outstanding questions still open are the detailed nature of the insulating phase (in particular regarding the partial suppression of localm o-

rem arkable suppression of  $T_{M TT}$  under pressure [6, 7]. We are grateful to J.-P. Pouget and L. Forro for stimulating our interest in this material, and acknow ledge many useful discussions with the Orsay experimental group (S. Fagot, P. Foury-Leylekian, J.-P. Pouget and S. Ravy), and also with P.A. Lee and T. G iam archi. C om putations were performed at ID R IS O rsay.

m ents and the eventualm agnetic ordering) as well as the

Note added. A fler the completion of this work, we became aware of a recent angle-resolved photoem ission study of BaVS<sub>3</sub> by S. M itrovic et al. supporting our prediction of a reduced  $k_F$  (A<sub>1g</sub>).

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- [24] Ref. [16] reported that without magnetic order, the lling of the A  $_{1\rm g}$  band is actually further increased, in comparison to LDA .
- [25] The QMC calculations were performed at temperatures signi cantly higher than the physical  $T_{M \mbox{ IT}}$  (cf. Figs. 3-5). However, we still think that the essential physics close to  $T_{M \mbox{ IT}}$  is captured. This is because the coherence scale for the broad  $A_{1g}$  band is already reached for elevated temperatures over m ost of the range of parameters that we have studied, and the crystal structure at  $T = 100 \mbox{ K}$  was used in the LDA calculations.

